NSN 5961-01-352-3481

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View Online at https://aerobasegroup.com/nsn/5961-01-352-3481 **Inclosure Material:** Ceramic or plastic **Overall Length:** Between 9.4 millimeters and 10.42 millimeters **Overall Height:** Between 2.19 millimeters and 2.38 millimeters **Overall Width:** Between 6.35 millimeters and 6.73 millimeters **Internal Configuration:** Field effect Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-252 **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, drain-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 8.00 amperes zero-gate-voltage source current pascal **Power Rating Per Characteristic:** 42.0 watts small-signal input power, common-collector preset **Terminal Type And Quantity:** 3 pin Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: